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#### Understanding [Embedded - DSP \(Digital Signal Processors\)](#)

[Embedded - DSP \(Digital Signal Processors\)](#) are specialized microprocessors designed to perform complex mathematical computations on digital signals in real-time. Unlike general-purpose processors, DSPs are optimized for high-speed numeric processing tasks, making them ideal for applications that require efficient and precise manipulation of digital data. These processors are fundamental in converting and processing signals in various forms, including audio, video, and communication signals, ensuring that data is accurately interpreted and utilized in embedded systems.

#### Applications of [Embedded - DSP \(Digital Signal Processors\)](#)

##### Details

Product Status	Obsolete
Type	Audio Processor
Interface	Host Interface, I <sup>2</sup> C, SAI, SPI
Clock Rate	100MHz
Non-Volatile Memory	ROM (192kB)
On-Chip RAM	11.25kB
Voltage - I/O	3.30V
Voltage - Core	3.30V
Operating Temperature	-40°C ~ 105°C (T <sub>J</sub> )
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	<a href="https://www.e-xfl.com/pro/item?MUrl=&amp;PartUrl=dspb56364af100">https://www.e-xfl.com/pro/item?MUrl=&amp;PartUrl=dspb56364af100</a>

## 1.1 Features

### 1.1.1 Digital Signal Processing Core

- 100 Million Instructions Per Second (MIPS) with an 100 MHz clock at 3.3V.
- Object Code Compatible with the 56000 core.
- Data ALU with a  $24 \times 24$  bit multiplier-accumulator and a 56-bit barrel shifter. 16-bit arithmetic support.
- Program Control with position independent code support and instruction cache support.
- Six-channel DMA controller.
- PLL based clocking with a wide range of frequency multiplications (1 to 4096), predivider factors (1 to 16) and power saving clock divider ( $2^i$ :  $i = 0$  to 7). Reduces clock noise.
- Internal address tracing support and OnCE™ for Hardware/Software debugging.
- JTAG port.
- Very low-power CMOS design, fully static design with operating frequencies down to DC.
- STOP and WAIT low-power standby modes.

### 1.1.2 On-Chip Memory Configuration

- $1.5K \times 24$  Bit Y-Data RAM.
- $1K \times 24$  Bit X-Data RAM.
- $8K \times 24$  Bit Program ROM.
- $0.5K \times 24$  Bit Program RAM and  $192 \times 24$  Bit Bootstrap ROM.
- $0.75K \times 24$  Bit from Y Data RAM can be switched to Program RAM resulting in up to  $1.25K \times 24$  Bit of Program RAM.

### 1.1.3 Off-Chip Memory Expansion

- External Memory Expansion Port with 8-bit data bus.
- Off-chip expansion up to  $2 \times 16M \times 8$ -bit word of Data/Program memory when using DRAM.
- Off-chip expansion up to  $2 \times 256k \times 8$ -bit word of Data/Program memory when using SRAM.
- Simultaneous glueless interface to SRAM and DRAM.

### 1.1.4 Peripheral Modules

- Enhanced Serial Audio Interface (ESAI): 6 serial lines, 4 selectable as receive or transmit and 2 transmit only, master or slave. I<sup>2</sup>S, Sony, AC97, network and other programmable protocols. Unused pins of ESAI may be used as GPIO lines.
- Serial Host Interface (SHI): SPI and I<sup>2</sup>C protocols, 10-word receive FIFO, support for 8, 16 and 24-bit words.
- Four dedicated GPIO lines.

### 1.1.5 Packaging

- 100-pin plastic TQFP package.

## 1.2 Documentation

**Table 1-1** lists the documents that provide a complete description of the DSP56364 and are required to design properly with the part. Documentation is available from a local Freescale distributor, a Freescale semiconductor sales office, a Freescale Literature Distribution Center, or through the Freescale DSP home page on the Internet (the source for the latest information).

**Table 1-1 DSP56364 Documentation**

Document Name	Description	Order Number
DSP56300 Family Manual	Detailed description of the 56000-family architecture and the 24-bit core processor and instruction set	DSP56300FM
DSP56364 User's Manual	Detailed description of memory, peripherals, and interfaces	DSP56364UM
DSP56364 Product Brief	Brief description of the chip	DSP56364P
DSP56364 Technical Data Sheet (this document)	Electrical and timing specifications; pin and package descriptions	DSP56364

## Reset, Stop, Mode Select, and Interrupt Timing

Table 3-7 Reset, Stop, Mode Select, and Interrupt Timing<sup>1</sup> (continued)

No.	Characteristics	Expression <sup>2</sup>	Min	Max	Unit
21	Delay from $\overline{WR}$ assertion to interrupt request deassertion for level sensitive fast interrupts <sup>6, 7</sup> <ul style="list-style-type: none"> <li>• DRAM for all WS</li> <li>• SRAM WS = 1</li> <li>• SRAM WS = 2, 3</li> <li>• SRAM WS <math>\geq</math> 4</li> </ul>	$(WS + 3.5) \times T_C - 10.94$ $(WS + 3.5) \times T_C - 10.94$ $(WS + 3) \times T_C - 10.94$ $(WS + 2.5) \times T_C - 10.94$	—	—	ns
24	Duration for $\overline{IRQA}$ assertion to recover from Stop state		5.9	—	
25	Delay from $\overline{IRQA}$ assertion to fetch of first instruction (when exiting Stop) <sup>3, 8</sup> <ul style="list-style-type: none"> <li>• PLL is not active during Stop (PCTL Bit 17 = 0) and Stop delay is enabled (OMR Bit 6 = 0)</li> <li>• PLL is not active during Stop (PCTL Bit 17 = 0) and Stop delay is not enabled (OMR Bit 6 = 1)</li> <li>• PLL is active during Stop (PCTL Bit 17 = 1) (Implies No Stop Delay)</li> </ul>	$PLC \times ET_C \times PDF + (128 K - PLC/2) \times T_C$ $PLC \times ET_C \times PDF + (23.75 \pm 0.5) \times T_C$ $(8.25 \pm 0.5) \times T_C$	1.3 232.5 ns 77.5	13.6 12.3 ms 87.5	ms
26	Duration of level sensitive $\overline{IRQA}$ assertion to ensure interrupt service (when exiting Stop) <sup>3, 8</sup> <ul style="list-style-type: none"> <li>• PLL is not active during Stop (PCTL Bit 17 = 0) and Stop delay is enabled (OMR Bit 6 = 0)</li> <li>• PLL is not active during Stop (PCTL Bit 17 = 0) and Stop delay is not enabled (OMR Bit 6 = 1)</li> <li>• PLL is active during Stop (PCTL Bit 17 = 1) (implies no Stop delay)</li> </ul>	$PLC \times ET_C \times PDF + (128 K - PLC/2) \times T_C$ $PLC \times ET_C \times PDF + (20.5 \pm 0.5) \times T_C$ $5.5 \times T_C$	13.6 12.3 55.0	—	ms ns
27	Interrupt Requests Rate <ul style="list-style-type: none"> <li>• ESAI, SCI</li> <li>• DMA</li> <li>• <math>\overline{IRQ}</math>, <math>\overline{NMI}</math> (edge trigger)</li> <li>• <math>\overline{IRQ}</math>, <math>\overline{NMI}</math> (level trigger)</li> </ul>	$12T_C$ $8T_C$ $8T_C$ $12T_C$	— — — —	120.0 80.0 80.0 120.0	ns ns ns ns
28	DMA Requests Rate <ul style="list-style-type: none"> <li>• Data read from ESAI, SCI</li> <li>• Data write to ESAI, SCI</li> <li>• <math>\overline{IRQ}</math>, <math>\overline{NMI}</math> (edge trigger)</li> </ul>	$6T_C$ $7T_C$ $3T_C$	— — —	60.0 70.0 30.0	ns ns ns

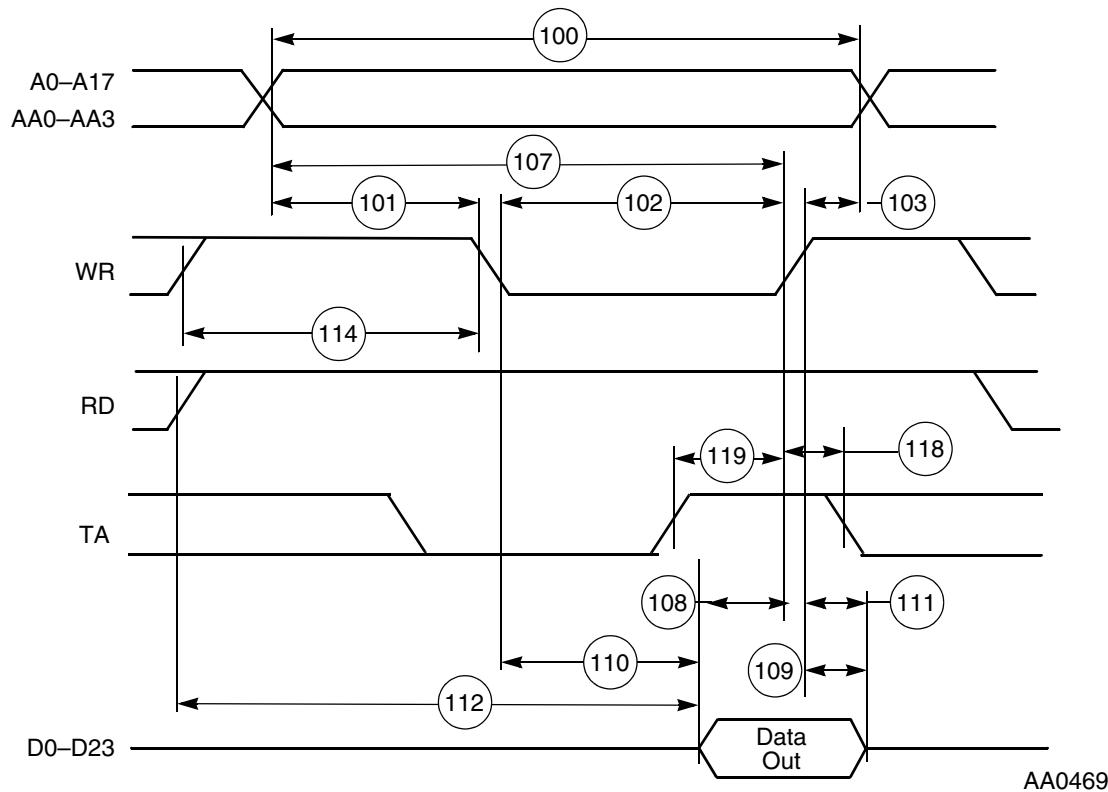


Figure 3-10 SRAM Write Access

### 3.10.2 DRAM Timing

The selection guides provided in [Figure 3-11](#) and [Figure 3-14](#) should be used for primary selection only. Final selection should be based on the timing provided in the following tables. As an example, the selection guide suggests that 4 wait states must be used for 100 MHz operation when using Page Mode DRAM. However, by using the information in the appropriate table, a designer may choose to evaluate whether fewer wait states might be used by determining which timing prevents operation at 100 MHz, running the chip at a slightly lower frequency (e.g., 95 MHz), using faster DRAM (if it becomes available), and control factors such as capacitive and resistive load to improve overall system performance.

**Table 3-11 DRAM Page Mode Timings, Three Wait States<sup>1, 2, 3</sup> (continued)**

No.	Characteristics	Symbol	Expression <sup>4</sup>	Min	Max	Unit
152	Last $\overline{RD}$ assertion to $\overline{RAS}$ deassertion	$t_{ROH}$	$3.5 \times T_C - 4.0$	31.0	—	ns
153	$\overline{RD}$ assertion to data valid	$t_{GA}$	$2.5 \times T_C - 7.0$	—	18.0	ns
154	$\overline{RD}$ deassertion to data not valid <sup>6</sup>	$t_{GZ}$		0.0	—	ns
155	$\overline{WR}$ assertion to data active		$0.75 \times T_C - 0.3$	7.2	—	ns
156	$\overline{WR}$ deassertion to data high impedance		$0.25 \times T_C$	—	2.5	ns

<sup>1</sup> The number of wait states for Page mode access is specified in the DCR.

<sup>2</sup> The refresh period is specified in the DCR.

<sup>3</sup> The asynchronous delays specified in the expressions are valid for DSP56364.

<sup>4</sup> All the timings are calculated for the worst case. Some of the timings are better for specific cases (e.g.,  $t_{PC}$  equals  $4 \times T_C$  for read-after-read or write-after-write sequences).

<sup>5</sup> BRW[1:0] (DRAM control register bits) defines the number of wait states that should be inserted in each DRAM out-of-page-access.

<sup>6</sup>  $\overline{RD}$  deassertion will always occur after  $\overline{CAS}$  deassertion; therefore, the restricted timing is  $t_{OFF}$  and not  $t_{GZ}$ .

**Table 3-12 DRAM Page Mode Timings, Four Wait States<sup>1, 2, 3</sup>**

No.	Characteristics	Symbol	Expression <sup>4</sup>	Min	Max	Unit
131	Page mode cycle time for two consecutive accesses of the same direction. Page mode cycle time for mixed (read and write) accesses.	$t_{PC}$	$2 \times T_C$ $1.25 \times T_C$	50.0 45.0	— —	ns ns
132	$\overline{CAS}$ assertion to data valid (read)	$t_{CAC}$	$2.75 \times T_C - 7.0$	—	20.5	ns
133	Column address valid to data valid (read)	$t_{AA}$	$3.75 \times T_C - 7.0$	—	30.5	ns
134	$\overline{CAS}$ deassertion to data not valid (read hold time)	$t_{OFF}$		0.0	—	ns
135	Last $\overline{CAS}$ assertion to $\overline{RAS}$ deassertion	$t_{RSH}$	$3.5 \times T_C - 4.0$	31.0	—	ns
136	Previous $\overline{CAS}$ deassertion to $\overline{RAS}$ deassertion	$t_{RHCP}$	$6 \times T_C - 4.0$	56.0	—	ns
137	$\overline{CAS}$ assertion pulse width	$t_{CAS}$	$2.5 \times T_C - 4.0$	21.0	—	ns
138	Last $\overline{CAS}$ deassertion to $\overline{RAS}$ assertion <sup>5</sup>	$t_{CRP}$	$2.75 \times T_C - 6.0$ $4.25 \times T_C - 6.0$ $5.25 \times T_C - 6.0$ $7.25 \times T_C - 6.0$	— — 46.5 66.5	— — — —	ns ns ns ns
139	$\overline{CAS}$ deassertion pulse width	$t_{CP}$	$2 \times T_C - 4.0$	16.0	—	ns

**Table 3-15 DRAM Out-of-Page and Refresh Timings, Eleven Wait States<sup>1, 2</sup> (continued)**

No.	Characteristics <sup>3</sup>	Symbol	Expression <sup>4</sup>	Min	Max	Unit
191	$\overline{RD}$ assertion to $\overline{RAS}$ deassertion	$t_{ROH}$	$11.5 \times T_C - 4.0$	111.0	—	ns
192	$\overline{RD}$ assertion to data valid	$t_{GA}$	$10 \times T_C - 7.0$	—	93.0	ns
193	$\overline{RD}$ deassertion to data not valid <sup>3</sup>	$t_{GZ}$		0.0	—	ns
194	$\overline{WR}$ assertion to data active		$0.75 \times T_C - 0.3$	7.2	—	ns
195	$\overline{WR}$ deassertion to data high impedance		$0.25 \times T_C$	—	2.5	ns

<sup>1</sup> The number of wait states for out-of-page access is specified in the DCR.

<sup>2</sup> The refresh period is specified in the DCR.

<sup>3</sup>  $\overline{RD}$  deassertion will always occur after  $\overline{CAS}$  deassertion; therefore, the restricted timing is  $t_{OFF}$  and not  $t_{GZ}$ .

<sup>4</sup> The asynchronous delays specified in the expressions are valid for DSP56364.

<sup>5</sup> Either  $t_{RCH}$  or  $t_{RRH}$  must be satisfied for read cycles.

**Table 3-16 DRAM Out-of-Page and Refresh Timings, Fifteen Wait States<sup>1, 2</sup>**

No.	Characteristics <sup>3</sup>	Symbol	Expression	Min	Max	Unit
157	Random read or write cycle time	$t_{RC}$	$16 \times T_C$	160.0	—	ns
158	$\overline{RAS}$ assertion to data valid (read)	$t_{RAC}$	$8.25 \times T_C - 5.7$	—	76.8	ns
159	$\overline{CAS}$ assertion to data valid (read)	$t_{CAC}$	$4.75 \times T_C - 5.7$	—	41.8	ns
160	Column address valid to data valid (read)	$t_{AA}$	$5.5 \times T_C - 5.7$	—	49.3	ns
161	$\overline{CAS}$ deassertion to data not valid (read hold time)	$t_{OFF}$	0.0	0.0	—	ns
162	$\overline{RAS}$ deassertion to $\overline{RAS}$ assertion	$t_{RP}$	$6.25 \times T_C - 4.0$	58.5	—	ns
163	$\overline{RAS}$ assertion pulse width	$t_{RAS}$	$9.75 \times T_C - 4.0$	93.5	—	ns
164	$\overline{CAS}$ assertion to $\overline{RAS}$ deassertion	$t_{RSH}$	$6.25 \times T_C - 4.0$	58.5	—	ns
165	$\overline{RAS}$ assertion to $\overline{CAS}$ deassertion	$t_{CSH}$	$8.25 \times T_C - 4.0$	78.5	—	ns
166	$\overline{CAS}$ assertion pulse width	$t_{CAS}$	$4.75 \times T_C - 4.0$	43.5	—	ns
167	$\overline{RAS}$ assertion to $\overline{CAS}$ assertion	$t_{RCD}$	$3.5 \times T_C \pm 2$	33.0	37.0	ns
168	$\overline{RAS}$ assertion to column address valid	$t_{RAD}$	$2.75 \times T_C \pm 2$	25.5	29.5	ns
169	$\overline{CAS}$ deassertion to $\overline{RAS}$ assertion	$t_{CRP}$	$7.75 \times T_C - 4.0$	73.5	—	ns
170	$\overline{CAS}$ deassertion pulse width	$t_{CP}$	$6.25 \times T_C - 4.0$	58.5	—	ns
171	Row address valid to $\overline{RAS}$ assertion	$t_{ASR}$	$6.25 \times T_C - 4.0$	58.5	—	ns
172	$\overline{RAS}$ assertion to row address not valid	$t_{RAH}$	$2.75 \times T_C - 4.0$	23.5	—	ns

Table 3-20 Enhanced Serial Audio Interface Timing (continued)

No.	Characteristics <sup>1, 2, 3</sup>	Symbol	Expression	Min	Max	Condition <sup>4</sup>	Unit
443	FSR input hold time after RXC falling edge	—	—	3.0 0.0	— —	x ck i ck a	ns
444	Flags input setup before RXC falling edge	—	—	0.0 19.0	— —	x ck i ck s	ns
445	Flags input hold time after RXC falling edge	—	—	6.0 0.0	— —	x ck i ck s	ns
446	TXC rising edge to FST out (bl) high	—	—	— —	29.0 15.0	x ck i ck	ns
447	TXC rising edge to FST out (bl) low	—	—	— —	31.0 17.0	x ck i ck	ns
448	TXC rising edge to FST out (wr) high <sup>6</sup>	—	—	— —	31.0 17.0	x ck i ck	ns
449	TXC rising edge to FST out (wr) low <sup>6</sup>	—	—	— —	33.0 19.0	x ck i ck	ns
450	TXC rising edge to FST out (wl) high	—	—	— —	30.0 16.0	x ck i ck	ns
451	TXC rising edge to FST out (wl) low	—	—	— —	31.0 17.0	x ck i ck	ns
452	TXC rising edge to data out enable from high impedance	—	—	— —	31.0 17.0	x ck i ck	ns
453	TXC rising edge to transmitter #0 drive enable assertion	—	—	— —	34.0 20.0	x ck i ck	ns
454	TXC rising edge to data out valid	—	$23 + 0.5 \times T_C$ 21.0	— —	28.0 21.0	x ck i ck	ns
455	TXC rising edge to data out high impedance <sup>7</sup>	—	—	— —	31.0 16.0	x ck i ck	ns
456	TXC rising edge to transmitter #0 drive enable deassertion <sup>7</sup>	—	—	— —	34.0 20.0	x ck i ck	ns
457	FST input (bl, wr) setup time before TXC falling edge <sup>6</sup>	—	—	2.0 21.0	— —	x ck i ck	ns
458	FST input (wl) to data out enable from high impedance	—	—	—	27.0	—	ns

## 4 Packaging

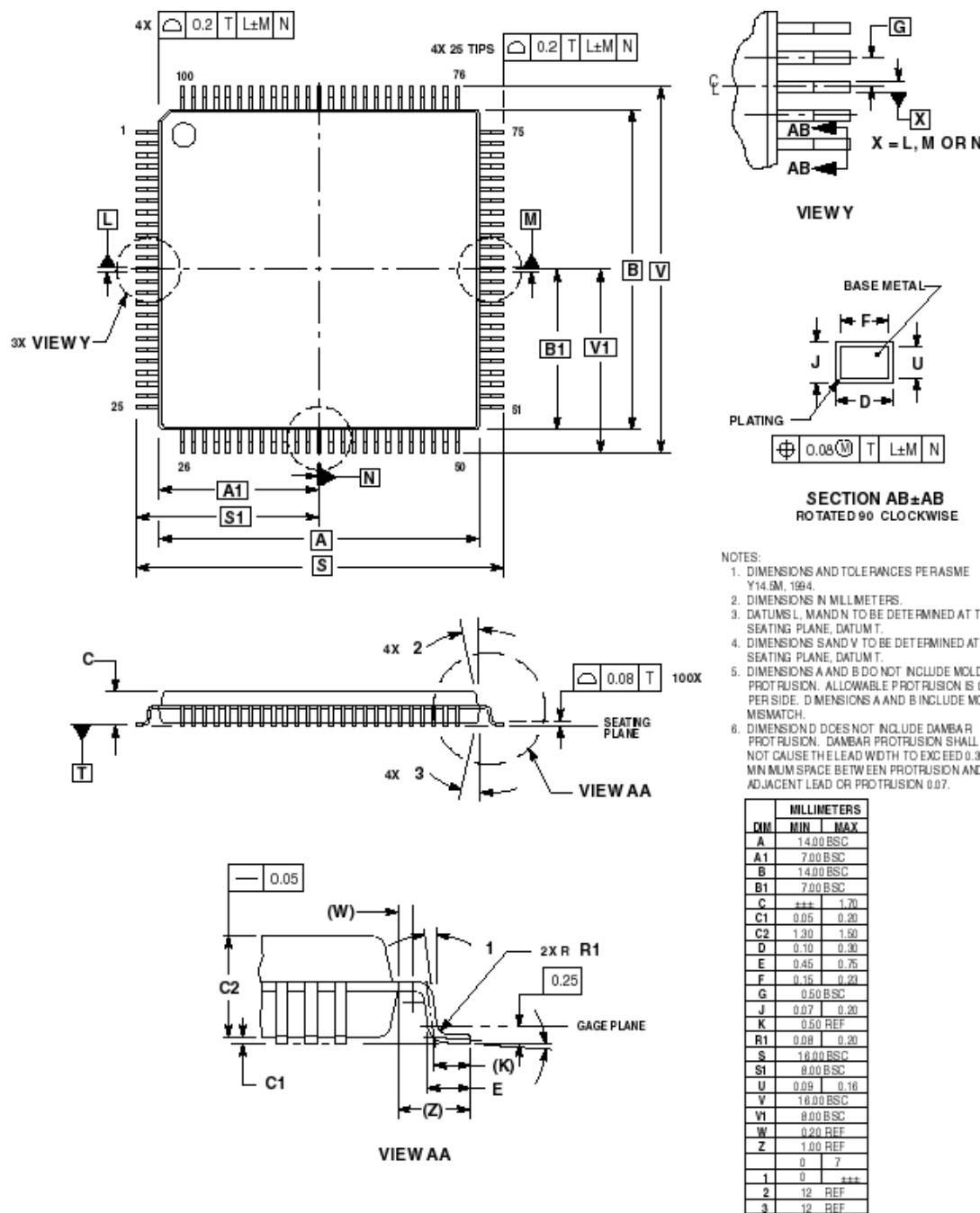
### 4.1 Pin-Out and Package Information

This section provides information about the available package for this product, including diagrams of the package pinouts and tables describing how the signals described in [Section 2, "Signal/Connection Descriptions"](#) are allocated for the package. The DSP56364 is available in a 100-pin TQFP package. [Table 4-1](#) and [Table 4-2](#) show the pin/name assignments for the packages.

#### 4.1.1 TQFP Package Description

Top view of the 100-pin TQFP package is shown in [Figure 4-1](#) with its pin-outs. The 100-pin TQFP package mechanical drawing is shown in [Figure 4-2](#).

## 4.1.2 TQFP Package Mechanical Drawing



CASE 983±02  
ISSUE E

DATE 01/30/96

Figure 4-2 DSP56364 100-pin TQFP Package

- All inputs must be terminated (i.e., not allowed to float) using CMOS levels, except for the three pins with internal pull-up resistors (TMS, TDI, TCK).
- Take special care to minimize noise levels on the  $V_{CCP}$  and  $GND_P$  pins.
- If multiple DSP56364 devices are on the same board, check for cross-talk or excessive spikes on the supplies due to synchronous operation of the devices.
- RESET must be asserted when the chip is powered up. A stable EXTAL signal must be supplied before deassertion of RESET.
- At power-up, ensure that the voltage difference between the 5 V tolerant pins and the chip  $V_{CC}$  never exceeds 3.95 V.

## 5.3 Power Consumption Considerations

Power dissipation is a key issue in portable DSP applications. Some of the factors which affect current consumption are described in this section. Most of the current consumed by CMOS devices is alternating current (ac), which is charging and discharging the capacitances of the pins and internal nodes.

Current consumption is described by the following formula:

$$I = C \times V \times f$$

where     $C$     = node/pin capacitance  
              $V$     = voltage swing  
              $f$     = frequency of node/pin toggle

### Example 1. Current Consumption

---

For a Port A address pin loaded with 50 pF capacitance, operating at 3.3 V, and with a 100 MHz clock, toggling at its maximum possible rate (50 MHz), the current consumption is

$$I = 50 \times 10^{-12} \times 3.3 \times 50 \times 10^6 = 8.25\text{mA}$$


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The maximum internal current ( $I_{CCI\max}$ ) value reflects the typical possible switching of the internal buses on best-case operation conditions, which is not necessarily a real application case. The typical internal current ( $I_{CCI\text{typ}}$ ) value reflects the average switching of the internal buses on typical operating conditions.

For applications that require very low current consumption, do the following:

- Set the EBD bit when not accessing external memory.
- Minimize external memory accesses and use internal memory accesses.
- Minimize the number of pins that are switching.
- Minimize the capacitive load on the pins.
- Connect the unused inputs to pull-up or pull-down resistors.
- Disable unused peripherals.

One way to evaluate power consumption is to use a current per MIPS measurement methodology to minimize specific board effects (i.e., to compensate for measured board current not caused by the DSP).

## Appendix A IBIS Model

```

IBIS Model
[IBIS Ver]          3.2
[File name]         56364_e.ibs
[File Rev]          e
[Date]              Feb 13, 2002
[Component]         56364
[Manufacturer]      Freescale SEMI CONDUCTOR Ltd.
[Package]
| variable          typ        min        max
R_pkg               45.0m     22.0m     75.0m
L_pkg               2.5nH     1.1nH     4.3nH
C_pkg               1.3pF     1.2pF     1.4pF
[Pin]    signal_name   model_name   R_pin      L_pin      C_pin
1       irqd_          ipad5v_io
2       irqb_          ipad5v_io
3       irqa_          ipad5v_io
4       fst             ipad5v_io
5       fsr             ipad5v_io
6       sckt            ipad5v_io
7       sckr            ipad5v_io
8       vccs            power
9       gnds            gnd
10      hckt            ipad5v_io
11      vcclq           power
12      gndq            gnd
13      hckr            ipad5v_io
14      sdo0            ipad5v_io
15      vcchq           power
16      sdo1            ipad5v_io
17      sdo2/sdi3       ipad5v_io
18      sdo3/sdi2       ipad5v_io
19      sdo4/sdi1       ipad5v_io
20      sdo5/sdi0       ipad5v_io
21      vccs            power
22      gnds            gnd
23      ss_/ha2         ipad5v_io
24      mosi/ha0         ipad5v_io
25      miso/sda         ipad5i_io
26      sck/scl         ipad5i_io
27      hreq_           ipad5i_io
28      pinit/nmi_       ipad5v_io
29      reset_          ipad5v_io
31      vccp            power
32      pcap            power
33      gndp            gnd
34      extal           ipadex_i
35      vcchq           power

```

```

94          gpio1           ipad5v_io
95          gpio2           ipad5v_io
96          gpio3           ipad5v_io
97          tdo             ipad5f_io
98          tdi             ipad5f_io
99          tck             ipad5f_io
100         tms             ipad5f_io

[Model]          ipad5f_io | """
Model_type      I/O
Vinl = 0.8
Vinh = 2
| variable     typ      min      max
C_comp          1.96p    1.87p    2.06p
| variable     typ      min      max
[Temperature Range] 40.0    0.0     120.0
| variable     typ      min      max
[Voltage Range]   3.30V   3.00V   3.60V
|
[Pulldown]
| pulldown in the table = pulldown subtract gnd_clamp
| Voltage      I(typ)   I(min)   I(max)
|
-3.30V        -142.303u -76.239u -215.182u
-3.20V        -149.700u -80.226u -226.432u
-3.10V        -157.861u -84.616u -238.866u
-3.00V        -166.908u -89.472u -252.678u
-2.90V        -176.992u -94.869u -268.107u
-2.80V        -188.295u -100.900u -285.446u
-2.70V        -201.049u -107.679u -305.068u
-2.60V        -215.545u -115.349u -327.446u
-2.50V        -232.155u -124.094u -353.191u
-2.40V        -251.367u -134.145u -383.107u
-2.30V        -273.825u -145.808u -418.273u
-2.20V        -300.403u -159.488u -460.167u
-2.10V        -332.314u -175.737u -510.874u
-2.00V        -371.286u -195.318u -573.418u
-1.90V        -419.868u -219.325u -652.360u
-1.80V        -481.968u -249.369u -754.892u
-1.70V        -563.882u -287.925u -893.013u
-1.60V        -676.382u -338.973u   -1.088m
-1.50V        -839.410u -409.300u   -1.383m
-1.40V        -1.094m  -511.367u   -1.873m
-1.30V        -1.537m  -670.350u   -2.819m
-1.20V        -2.451m  -943.845u   -5.162m
-1.10V        -4.857m  -1.486m   -12.214m
-1.00V        -10.606m -2.746m   -20.764m
-0.90V        -14.267m -5.259m   -21.749m
-0.80V        -13.851m -7.108m   -20.142m
-0.70V        -12.481m -7.168m   -18.211m
-0.60V        -10.883m -6.348m   -15.981m
-0.50V        -9.156m  -5.339m   -13.503m
-0.40V        -7.378m  -4.288m   -10.922m
-0.30V        -5.572m  -3.224m   -8.282m
-0.20V        -3.741m  -2.154m   -5.584m

```

5.40V	71.005m	39.460m	115.267m
5.50V	70.389m	39.508m	115.917m
5.60V	70.321m	39.552m	116.139m
5.70V	70.361m	39.595m	114.582m
5.80V	70.422m	39.634m	111.344m
5.90V	70.489m	39.672m	110.612m
6.00V	70.557m	39.708m	110.449m
6.10V	70.624m	39.743m	110.455m
6.20V	70.690m	39.777m	110.515m
6.30V	70.753m	39.812m	110.595m
6.40V	70.817m	39.848m	110.686m
6.50V	70.881m	39.886m	110.783m
6.60V	70.949m	39.929m	110.885m
[Pullup]			
pullup in the table = pullup subtract power_clamp			
Voltage	I(typ)	I(min)	I(max)
-3.30V	75.797u	7.914u	161.477u
-3.20V	90.464u	17.699u	181.779u
-3.10V	105.160u	27.445u	202.314u
-3.00V	119.836u	37.119u	223.007u
-2.90V	134.451u	46.694u	243.785u
-2.80V	148.966u	56.144u	264.581u
-2.70V	163.342u	65.447u	285.332u
-2.60V	177.543u	74.582u	305.982u
-2.50V	191.536u	83.527u	326.474u
-2.40V	205.285u	92.262u	346.757u
-2.30V	218.754u	100.766u	366.776u
-2.20V	231.907u	109.016u	386.478u
-2.10V	244.706u	116.988u	405.807u
-2.00V	257.106u	124.659u	424.699u
-1.90V	269.061u	131.998u	443.089u
-1.80V	280.519u	138.978u	460.899u
-1.70V	291.423u	145.565u	478.046u
-1.60V	301.710u	151.723u	494.457u
-1.50V	311.348u	157.417u	521.406u
-1.40V	729.899u	162.626u	1.612m
-1.30V	10.510m	445.517u	14.832m
-1.20V	9.629m	6.444m	13.576m
-1.10V	8.670m	5.833m	12.231m
-1.00V	7.693m	5.190m	10.854m
-0.90V	6.732m	4.551m	9.483m
-0.80V	5.825m	3.942m	8.169m
-0.70V	5.004m	3.382m	6.971m
-0.60V	4.261m	2.869m	5.921m
-0.50V	3.549m	2.381m	4.953m
-0.40V	2.841m	1.902m	3.978m
-0.30V	2.135m	1.426m	2.987m
-0.20V	1.437m	951.489u	2.003m
-0.10V	722.340u	478.341u	1.005m
-0.00V	22.329p	3.311p	24.081p
0.10V	-708.556u	-465.927u	-990.647u
0.20V	-1.377m	-903.637u	-1.943m
0.30V	-2.007m	-1.319m	-2.832m

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5.80V      -1.221 -849.071m   -1.102
5.90V      -1.303 -893.931m   -1.197
6.10V      -1.466 -983.765m   -1.388
6.20V      -1.548    -1.029   -1.483
6.30V      -1.630    -1.074   -1.579
6.40V      -1.711    -1.119   -1.675
6.50V      -1.793    -1.164   -1.771
6.60V      -1.875    -1.209   -1.867
|
[Ramp]
|Voltage      I(typ)      I(min)      I(max)
|
dV/dt_f    2.04/134.002p 1.86/235.405p 2.23/85.874p
|
dV/dt_r    2.05/194.838p 1.86/341.412p 2.23/118.822p
R_load=10000ohms
| R_load was connected to ground for Ramp_up test and power for Ramp_dn test
|
|End model
[Model]          ipada_3st           | ""
Model_type      3-state
|
| variable      typ        min        max
C_comp          2.32p     2.17p     2.48p
|
| variable      typ        min        max
[Temperature Range] 40.0      0.0      120.0
|
| variable      typ        min        max
[Voltage Range]  3.30V     3.00V     3.60V
|
[Pulldown]
| pulldown in the table = pulldown subtract gnd_clamp
|Voltage      I(typ)      I(min)      I(max)
|
-3.30V      -157.134u  -99.256u  -219.000u
-3.20V      -165.037u  -104.127u  -230.250u
-3.10V      -173.749u  -109.479u  -242.685u
-3.00V      -183.400u  -115.386u  -256.500u
-2.90V      -194.148u  -121.936u  -271.934u
-2.80V      -206.189u  -129.240u  -289.286u
-2.70V      -219.766u  -137.431u  -308.933u
-2.60V      -235.190u  -146.680u  -331.355u
-2.50V      -252.856u  -157.199u  -357.176u
-2.40V      -273.283u  -169.265u  -387.219u
-2.30V      -297.162u  -183.236u  -422.595u
-2.20V      -325.427u  -199.590u  -464.837u
-2.10V      -359.384u  -218.976u  -516.117u
-2.00V      -400.901u  -242.299u  -579.623u
-1.90V      -452.750u  -270.851u  -660.217u
-1.80V      -519.217u  -306.549u  -765.681u
-1.70V      -607.277u  -352.346u  -909.270u
-1.60V      -729.045u  -413.024u  -1.115m
-1.50V      -907.407u  -496.811u  -1.434m
-1.40V      -1.191m   -619.011u  -1.987m
-1.30V      -1.699m   -811.079u  -3.133m
-1.20V      -2.799m   -1.146m   -6.243m
-1.10V      -5.689m   -1.822m  -12.974m

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-0.50V	5.109m	3.441m	7.052m
-0.40V	4.082m	2.746m	5.644m
-0.30V	3.056m	2.053m	4.233m
-0.20V	2.033m	1.363m	2.821m
-0.10V	1.014m	678.856u	1.410m
-0.00V	58.687e-18	58.622e-18	117.504e-18
0.10V	-987.106u	-655.604u	-1.381m
0.20V	-1.928m	-1.274m	-2.709m
0.30V	-2.828m	-1.859m	-3.988m
0.40V	-3.685m	-2.412m	-5.216m
0.50V	-4.499m	-2.931m	-6.392m
0.60V	-5.269m	-3.416m	-7.516m
0.70V	-5.994m	-3.866m	-8.587m
0.80V	-6.673m	-4.280m	-9.602m
0.90V	-7.306m	-4.658m	-10.561m
1.00V	-7.890m	-4.999m	-11.461m
1.10V	-8.424m	-5.301m	-12.302m
1.20V	-8.907m	-5.563m	-13.081m
1.30V	-9.339m	-65.539m	-13.798m
1.40V	-110.103m	-67.611m	-154.438m
1.50V	-113.807m	-69.311m	-170.370m
1.60V	-117.010m	-70.713m	-176.323m
1.70V	-119.783m	-71.893m	-181.647m
1.80V	-122.195m	-72.910m	-186.387m
1.90V	-124.297m	-73.804m	-190.581m
2.00V	-126.131m	-74.599m	-194.261m
2.10V	-127.733m	-75.311m	-197.468m
2.20V	-129.139m	-75.954m	-200.255m
2.30V	-130.384m	-76.540m	-202.683m
2.40V	-131.498m	-77.077m	-204.814m
2.50V	-132.504m	-77.575m	-206.704m
2.60V	-133.423m	-78.037m	-208.399m
2.70V	-134.270m	-78.470m	-209.937m
2.80V	-135.057m	-78.877m	-211.346m
2.90V	-135.792m	-79.261m	-212.650m
3.00V	-136.483m	-79.625m	-213.864m
3.10V	-137.136m	-79.971m	-215.004m
3.20V	-137.756m	-80.302m	-216.079m
3.30V	-138.345m	-80.617m	-217.098m
3.40V	-138.908m	-80.920m	-218.067m
3.50V	-139.447m	-81.210m	-218.993m
3.60V	-139.964m	-81.490m	-219.880m
3.70V	-140.462m	-81.761m	-220.732m
3.80V	-140.943m	-82.022m	-221.552m
3.90V	-141.408m	-82.277m	-222.344m
4.00V	-141.860m	-82.525m	-223.112m
4.10V	-142.300m	-82.769m	-223.858m
4.20V	-142.733m	-83.010m	-224.586m
4.30V	-143.159m	-83.250m	-225.300m
4.40V	-143.585m	-83.493m	-226.006m
4.50V	-144.013m	-83.740m	-226.709m
4.60V	-144.449m	-83.996m	-227.417m
4.70V	-144.899m	-84.265m	-228.137m
4.80V	-145.370m	-84.551m	-228.879m
4.90V	-145.871m	-84.861m	-229.656m

0.30V	-16.468p	-745.765p	-10.874p
0.40V	-13.353p	-683.799p	-8.234p
0.50V	-10.247p	-622.802p	-5.595p
0.60V	-7.147p	-562.404p	-2.956p
0.70V	-4.050p	-502.414p	-318.962f
0.80V	-955.896f	-442.712p	2.318p
0.90V	2.136p	-383.217p	4.954p
1.10V	8.315p	-264.634p	10.227p
1.20V	11.404p	-205.467p	12.862p
1.30V	14.492p	-146.346p	15.498p
1.40V	17.579p	-87.245p	18.133p
1.50V	20.666p	-28.141p	20.768p
1.60V	23.754p	30.987p	23.404p
1.70V	26.841p	90.164p	26.039p
1.80V	29.929p	149.414p	28.674p
1.90V	33.018p	208.769p	31.310p
2.10V	39.198p	327.949p	36.581p
2.20V	42.291p	387.873p	39.216p
2.30V	45.385p	448.012p	41.852p
2.40V	48.483p	507.296p	44.489p
2.50V	51.583p	563.856p	47.125p
2.60V	54.673p	619.785p	49.762p
2.70V	57.468p	676.156p	52.401p
2.80V	59.647p	733.868p	55.040p
2.90V	61.717p	807.258p	57.675p
3.10V	65.859p	5.906n	61.928p
3.20V	68.003p	59.801n	63.585p
3.30V	72.601p	620.266n	65.236p
<hr/>			
[POWER_clamp]			
<hr/>			
Voltage	I (typ)	I (min)	I (max)
<hr/>			
3.30V	-27.709p	-598.098n	-10.874p
3.40V	-92.071p	-6.086u	-13.516p
3.50V	-1.699n	-53.601u	-16.163p
3.60V	-37.668n	-397.909u	-18.939p
3.70V	-780.351n	-3.288m	-29.683p
3.80V	-14.514u	-16.226m	-411.332p
3.90V	-156.838u	-45.305m	-15.437n
4.10V	-3.535m	-142.138m	-18.044u
4.20V	-19.457m	-198.614m	-271.662u
4.30V	-69.631m	-257.221m	-1.613m
4.40V	-153.494m	-317.129m	-4.650m
4.50V	-252.314m	-377.904m	-11.215m
4.60V	-357.354m	-439.297m	-43.562m
4.70V	-465.583m	-501.149m	-127.373m
4.80V	-575.715m	-563.357m	-240.395m
4.90V	-687.103m	-625.847m	-363.667m
5.10V	-912.311m	-751.475m	-621.897m
5.20V	-1.026	-814.544m	-753.859m
5.30V	-1.140	-877.750m	-886.904m
5.40V	-1.254	-941.073m	-1.021
5.50V	-1.368	-1.004	-1.155
5.60V	-1.483	-1.068	-1.290

-0.80V	8.032m	4.727m	11.029m
-0.70V	7.118m	4.754m	9.778m
-0.60V	6.128m	4.128m	8.443m
-0.50V	5.109m	3.441m	7.052m
-0.40V	4.082m	2.746m	5.644m
-0.30V	3.056m	2.053m	4.233m
-0.20V	2.033m	1.363m	2.821m
-0.10V	1.014m	678.856u	1.410m
-0.00V	58.687e-18	58.622e-18	117.504e-18
0.10V	-987.106u	-655.604u	-1.381m
0.20V	-1.928m	-1.274m	-2.709m
0.30V	-2.828m	-1.859m	-3.988m
0.40V	-3.685m	-2.412m	-5.216m
0.50V	-4.499m	-2.931m	-6.392m
0.60V	-5.269m	-3.416m	-7.516m
0.70V	-5.994m	-3.866m	-8.587m
0.80V	-6.673m	-4.280m	-9.602m
0.90V	-7.306m	-4.658m	-10.561m
1.00V	-7.890m	-4.999m	-11.461m
1.10V	-8.424m	-5.301m	-12.302m
1.20V	-8.907m	-5.563m	-13.081m
1.30V	-9.339m	-65.539m	-13.798m
1.40V	-110.103m	-67.611m	-154.438m
1.50V	-113.807m	-69.311m	-170.370m
1.60V	-117.010m	-70.713m	-176.323m
1.70V	-119.783m	-71.893m	-181.647m
1.80V	-122.195m	-72.910m	-186.387m
1.90V	-124.297m	-73.804m	-190.581m
2.00V	-126.131m	-74.599m	-194.261m
2.10V	-127.733m	-75.311m	-197.468m
2.20V	-129.139m	-75.954m	-200.255m
2.30V	-130.384m	-76.540m	-202.683m
2.40V	-131.498m	-77.077m	-204.814m
2.50V	-132.504m	-77.575m	-206.704m
2.60V	-133.423m	-78.037m	-208.399m
2.70V	-134.270m	-78.470m	-209.937m
2.80V	-135.057m	-78.877m	-211.346m
2.90V	-135.792m	-79.261m	-212.650m
3.00V	-136.483m	-79.625m	-213.864m
3.10V	-137.136m	-79.971m	-215.004m
3.20V	-137.756m	-80.302m	-216.079m
3.30V	-138.345m	-80.617m	-217.098m
3.40V	-138.908m	-80.920m	-218.067m
3.50V	-139.447m	-81.210m	-218.993m
3.60V	-139.964m	-81.490m	-219.880m
3.70V	-140.462m	-81.761m	-220.732m
3.80V	-140.943m	-82.022m	-221.552m
3.90V	-141.408m	-82.277m	-222.344m
4.00V	-141.860m	-82.525m	-223.112m
4.10V	-142.300m	-82.769m	-223.858m
4.20V	-142.733m	-83.010m	-224.586m
4.30V	-143.159m	-83.250m	-225.300m
4.40V	-143.585m	-83.493m	-226.006m
4.50V	-144.013m	-83.740m	-226.709m
4.60V	-144.449m	-83.996m	-227.417m

4.70V	-144.899m	-84.265m	-228.137m
4.80V	-145.370m	-84.551m	-228.879m
4.90V	-145.871m	-84.861m	-229.656m
5.00V	-146.411m	-85.200m	-230.481m
5.10V	-147.001m	-85.575m	-231.368m
5.20V	-147.652m	-85.993m	-232.336m
5.30V	-148.379m	-86.464m	-233.404m
5.40V	-149.195m	-86.995m	-234.592m
5.50V	-150.115m	-87.597m	-235.924m
5.60V	-151.157m	-88.280m	-237.426m
5.70V	-152.339m	-89.054m	-239.124m
5.80V	-153.678m	-89.930m	-241.046m
5.90V	-155.194m	-90.921m	-243.223m
6.00V	-156.907m	-92.038m	-245.685m
6.10V	-158.839m	-93.294m	-248.465m
6.20V	-161.011m	-94.701m	-251.595m
6.30V	-163.444m	-96.273m	-255.109m
6.40V	-166.160m	-98.023m	-259.041m
6.50V	-169.182m	-99.963m	-263.425m
6.60V	-172.531m	-102.106m	-268.293m
[GND_clamp]			
Voltage	I (typ)	I (min)	I (max)
-3.30V	-2.637	-1.514	-3.063
-3.20V	-2.521	-1.451	-2.926
-3.10V	-2.406	-1.387	-2.789
-2.90V	-2.174	-1.259	-2.515
-2.80V	-2.059	-1.195	-2.378
-2.70V	-1.943	-1.132	-2.242
-2.60V	-1.828	-1.068	-2.105
-2.50V	-1.713	-1.004	-1.969
-2.40V	-1.598	-941.073m	-1.833
-2.30V	-1.483	-877.750m	-1.697
-2.20V	-1.368	-814.544m	-1.561
-2.10V	-1.254	-751.475m	-1.425
-1.90V	-1.026	-625.847m	-1.155
-1.80V	-912.311m	-563.357m	-1.021
-1.70V	-799.377m	-501.149m	-886.904m
-1.60V	-687.103m	-439.297m	-753.859m
-1.50V	-575.715m	-377.904m	-621.897m
-1.40V	-465.583m	-317.129m	-491.519m
-1.30V	-357.354m	-257.221m	-363.667m
-1.20V	-252.314m	-198.614m	-240.395m
-1.10V	-153.494m	-142.138m	-127.373m
-0.90V	-19.457m	-45.305m	-11.215m
-0.80V	-3.535m	-16.226m	-4.650m
-0.70V	-877.640u	-3.288m	-1.613m
-0.60V	-156.838u	-397.909u	-271.662u
-0.50V	-14.514u	-53.601u	-18.044u
-0.40V	-780.351n	-6.086u	-560.308n
-0.30V	-37.668n	-598.098n	-15.437n
-0.20V	-1.699n	-55.739n	-411.332p
-0.10V	-92.071p	-5.410n	-29.683p

0.00V	-27.709p	-1.212n	-18.939p
0.10V	-22.802p	-890.771p	-16.163p
0.20V	-19.598p	-810.054p	-13.516p
0.30V	-16.468p	-745.765p	-10.874p
0.40V	-13.353p	-683.799p	-8.234p
0.50V	-10.247p	-622.802p	-5.595p
0.60V	-7.147p	-562.404p	-2.956p
0.70V	-4.050p	-502.414p	-318.962f
0.80V	-955.896f	-442.712p	2.318p
0.90V	2.136p	-383.217p	4.954p
1.10V	8.315p	-264.634p	10.227p
1.20V	11.404p	-205.467p	12.862p
1.30V	14.492p	-146.346p	15.498p
1.40V	17.579p	-87.245p	18.133p
1.50V	20.666p	-28.141p	20.768p
1.60V	23.754p	30.987p	23.404p
1.70V	26.841p	90.164p	26.039p
1.80V	29.929p	149.414p	28.674p
1.90V	33.018p	208.769p	31.310p
2.10V	39.198p	327.949p	36.581p
2.20V	42.291p	387.873p	39.216p
2.30V	45.385p	448.012p	41.852p
2.40V	48.483p	507.296p	44.489p
2.50V	51.583p	563.856p	47.125p
2.60V	54.673p	619.785p	49.762p
2.70V	57.468p	676.156p	52.401p
2.80V	59.647p	733.868p	55.040p
2.90V	61.717p	807.258p	57.675p
3.10V	65.859p	5.906n	61.928p
3.20V	68.003p	59.801n	63.585p
3.30V	72.601p	620.266n	65.236p
[POWER_clamp]			
Voltage	I (typ)	I (min)	I (max)
3.30V	-27.709p	-598.098n	-10.874p
3.40V	-92.071p	-6.086u	-13.516p
3.50V	-1.699n	-53.601u	-16.163p
3.60V	-37.668n	-397.909u	-18.939p
3.70V	-780.351n	-3.288m	-29.683p
3.80V	-14.514u	-16.226m	-411.332p
3.90V	-156.838u	-45.305m	-15.437n
4.10V	-3.535m	-142.138m	-18.044u
4.20V	-19.457m	-198.614m	-271.662u
4.30V	-69.631m	-257.221m	-1.613m
4.40V	-153.494m	-317.129m	-4.650m
4.50V	-252.314m	-377.904m	-11.215m
4.60V	-357.354m	-439.297m	-43.562m
4.70V	-465.583m	-501.149m	-127.373m
4.80V	-575.715m	-563.357m	-240.395m
4.90V	-687.103m	-625.847m	-363.667m
5.10V	-912.311m	-751.475m	-621.897m
5.20V	-1.026	-814.544m	-753.859m
5.30V	-1.140	-877.750m	-886.904m

-1.30V	-298.248m	-214.579m	-300.867m
-1.20V	-212.028m	-166.582m	-200.187m
-1.10V	-130.668m	-120.248m	-107.496m
-0.90V	-17.375m	-40.029m	-8.803m
-0.80V	-2.837m	-14.886m	-3.451m
-0.70V	-656.331u	-3.014m	-1.195m
-0.60V	-116.521u	-336.317u	-201.636u
-0.50V	-10.789u	-41.964u	-13.420u
-0.40V	-580.051n	-4.632u	-416.799n
-0.30V	-27.994n	-450.005n	-11.484n
-0.20V	-1.269n	-41.862n	-311.158p
-0.10V	-74.463p	-4.218n	-27.092p
0.00V	-26.215p	-1.078n	-18.737p
0.10V	-22.114p	-826.325p	-16.303p
0.20V	-19.278p	-754.146p	-13.966p
0.30V	-16.497p	-694.188p	-11.632p
0.40V	-13.726p	-635.953p	-9.300p
0.50V	-10.963p	-578.437p	-6.968p
0.60V	-8.203p	-521.365p	-4.637p
0.70V	-5.446p	-464.595p	-2.307p
0.80V	-2.691p	-408.039p	22.980f
0.90V	62.079f	-351.636p	2.353p
1.10V	5.566p	-239.133p	7.011p
1.20V	8.316p	-182.975p	9.340p
1.30V	11.067p	-126.851p	11.669p
1.40V	13.817p	-70.743p	13.998p
1.50V	16.567p	-14.634p	16.327p
1.60V	19.317p	41.493p	18.656p
1.70V	22.067p	97.654p	20.985p
1.80V	24.817p	153.868p	23.313p
1.90V	27.568p	210.159p	25.642p
2.10V	33.072p	323.083p	30.300p
2.20V	35.825p	379.789p	32.629p
2.30V	38.581p	436.650p	34.958p
2.40V	41.339p	492.867p	37.288p
2.50V	44.098p	547.026p	39.618p
2.60V	46.849p	600.695p	41.948p
2.70V	49.356p	654.682p	44.279p
2.80V	51.378p	709.650p	46.611p
2.90V	53.315p	776.122p	48.939p
3.10V	57.193p	4.552n	52.772p
3.20V	59.183p	44.522n	54.319p
3.30V	62.959p	466.732n	55.861p
[POWER_clamp]			
Voltage	I (typ)	I (min)	I (max)
3.30V	-26.215p	-450.005n	-11.632p
3.40V	-74.463p	-4.632u	-13.966p
3.50V	-1.269n	-41.964u	-16.303p
3.60V	-27.994n	-336.317u	-18.737p
3.70V	-580.051n	-3.014m	-27.092p
3.80V	-10.789u	-14.886m	-311.158p
3.90V	-116.521u	-40.029m	-11.484n